

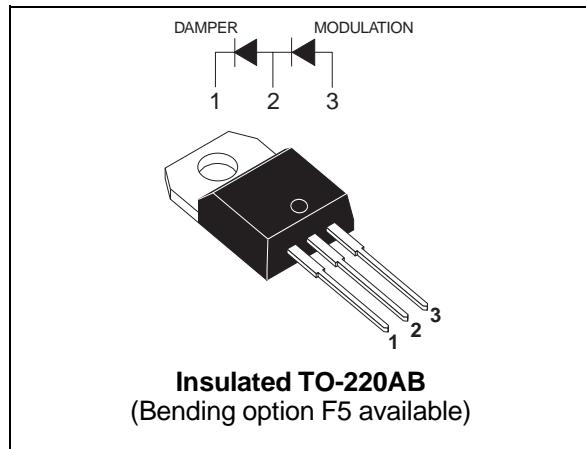
DAMPER + MODULATION DIODE FOR VIDEO

MAIN PRODUCT CHARACTERISTICS

	MODUL	DAMPER
I_{F(AV)}	3 A & 6 A	5 A & 6 A
V_{RRM}	600 V	1500 V
t_{rr}	50 ns	135 ns
V_{F(max)}	1.5 V	1.35 V

FEATURES AND BENEFITS

- FULL KIT IN ONE PACKAGE
- HIGH BREAKDOWN VOLTAGE CAPABILITY
- VERY FAST RECOVERY DIODE
- SPECIFIED TURN ON SWITCHING CHARACTERISTICS
- LOW STATIC AND PEAK FORWARD VOLTAGE DROP FOR LOW DISSIPATION
- INSULATED VERSION:
Insulated voltage = 2500 V_{RMS}
Capacitance = 7 pF
- PLANAR TECHNOLOGY ALLOWING HIGH QUALITY AND BEST ELECTRICAL CHARACTERISTICS
- OUTSTANDING PERFORMANCE OF WELL PROVEN DTV AS DAMPER AND TURBOSWITCH™ AS MODULATION



DESCRIPTION

High voltage semiconductor especially designed for horizontal deflection stage in standard and high resolution video display with E/W correction.

The insulated TO-220AB package includes both the DAMPER diode and the MODULATION diode. Assembled on automated line, it offers excellent insulating and dissipating characteristics, thanks to the internal ceramic insulation layer.

ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter	Value		Unit
		MODUL	DAMPER	
V _{RRM}	Repetitive peak reverse voltage	600	1500	V
I _{FSM}	Surge non repetitive forward current tp = 10 ms sinusoidal	DMV16	50	A
		DMV32	60	
		DMV56	60	
T _{stg}	Storage temperature range	- 40 to + 150		°C
T _j	Maximum operating junction temperature	150		

DMV series

THERMAL RESISTANCES

Symbol	Parameter	Value			Unit
		DMV16	DMV32	DMV56	
R _{th(j-c)}	Damper junction to case	5.3	4.8	3.6	°C/W
R _{th(j-c)}	Modulation junction to case	6.5	5.3	5.3	
R _{th(c)}	Coupling	0.2	0.2	0.2	
R _{th(j-c)}	Total as per full I _{F(AV)} maximum ratings	6.0	5.1	4.5	

STATIC ELECTRICAL CHARACTERISTICS OF THE DAMPER DIODES

Symbol	Parameter	Test conditions	Value				Unit	
			T _j = 25°C		T _j = 125°C			
			Typ.	Max.	Typ.	Max.		
V _F *	Forward voltage drop	I _F = 5 A	DMV16		1.6	1.0	1.5	V
		I _F = 6 A	DMV32		1.5	1.1	1.35	
		I _F = 6 A	DMV56		1.8	1.1	1.5	
I _R **	Reverse leakage current	V _R = V _{RRM}	DMV16		60	100	500	μA
			DMV32		100	100	1000	
			DMV56		100	100	1000	

Pulse test : * tp = 380 μs, δ < 2%

** tp = 5 ms, δ < 2%

To evaluate the maximum conduction losses of the DAMPER diode use the following equations :

$$\text{DMV16: } P = 1.14 \times I_{F(AV)} + 0.072 \times I_{F}^2(\text{RMS})$$

$$\text{DMV32: } P = 1.069 \times I_{F(AV)} + 0.047 \times I_{F}^2(\text{RMS})$$

$$\text{DMV56: } P = 1.15 \times I_{F(AV)} + 0.059 \times I_{F}^2(\text{RMS})$$

STATIC ELECTRICAL CHARACTERISTICS OF THE MODULATION DIODE

Symbol	Parameter	Test conditions	Value				Unit	
			T _j = 25°C		T _j = 125°C			
			Typ.	Max.	Typ.	Max.		
V _F *	Forward voltage drop	I _F = 3A	DMV16		1.4	1	1.3	V
		I _F = 5A	DMV32		1.75	1.2	1.5	
		I _F = 5A	DMV56		1.75	1.2	1.5	
I _R **	Reverse leakage current	V _R = 480V	DMV16		20	150	500	μA
			DMV32		100	600	2000	
			DMV56		100	600	2000	

Pulse test : * tp = 380 μs, δ < 2%

** tp = 5 ms, δ < 2%

To evaluate the maximum conduction losses of the MODULATION diode use the following equations :

$$\text{DMV16: } P = 1.06 \times I_{F(AV)} + 0.08 \times I_{F}^2(\text{RMS})$$

$$\text{DMV32: } P = 1.15 \times I_{F(AV)} + 0.07 \times I_{F}^2(\text{RMS})$$

$$\text{DMV56: } P = 1.15 \times I_{F(AV)} + 0.07 \times I_{F}^2(\text{RMS})$$

RECOVERY CHARACTERISTICS OF THE DAMPER DIODE

Symbol	Parameter	Test conditions			Value		Unit
		Typ.	Max.				
t_{rr}	Reverse recovery time	$I_F = 100\text{mA}$ $I_R = 100\text{mA}$ $I_{RR} = 10\text{mA}$	$T_j = 25^\circ\text{C}$	DMV16	1500		ns
				DMV32	850		
				DMV56	750		
t_{rr}	Reverse recovery time	$I_F = 1\text{A}$ $dI_F/dt = -50\text{A}/\mu\text{s}$ $V_R = 30\text{V}$	$T_j = 25^\circ\text{C}$	DMV16	200	300	ns
				DMV32	130	175	
				DMV56	110	135	

RECOVERY CHARACTERISTICS OF THE MODULATION DIODE

Symbol	Parameter	Test conditions			Value		Unit
		Typ.	Max.				
t_{rr}	Reverse recovery time	$I_F = 100\text{mA}$ $I_R = 100\text{mA}$ $I_{RR} = 10\text{mA}$	$T_j = 25^\circ\text{C}$	DMV16	210	650	ns
				DMV32	110	350	
				DMV56	110	350	
t_{rr}	Reverse recovery time	$I_F = 1\text{A}$ $dI_F/dt = -50\text{A}/\mu\text{s}$ $V_R = 30\text{V}$	$T_j = 25^\circ\text{C}$	DMV16		95	ns
				DMV32		50	
				DMV56		50	

TURN-ON SWITCHING CHARACTERISTICS OF THE DAMPER DIODE

Symbol	Parameter	Test conditions			Value		Unit
		Typ.	Max.				
t_{fr}	Forward recovery time	$I_F = 6\text{A}$ $dI_F/dt = 80\text{A}/\mu\text{s}$ $V_{FR} = 3\text{V}$	$T_j = 100^\circ\text{C}$	DMV16	350		ns
				DMV32	570		
				DMV56	350		
V_{FP}	Peak forward voltage	$I_F = 6\text{A}$ $dI_F/dt = 80\text{A}/\mu\text{s}$	$T_j = 100^\circ\text{C}$	DMV16	25	34	V
				DMV32	21	28	
				DMV56	19	26	

TURN-ON SWITCHING CHARACTERISTICS OF THE MODULATION DIODE

Symbol	Parameter	Test conditions			Value		Unit
		Typ.	Max.				
t_{fr}	Forward recovery time	$I_F = 3\text{A}$ $dI_F/dt = 80\text{A}/\mu\text{s}$ $V_{FR} = 3\text{V}$	$T_j = 100^\circ\text{C}$	DMV16		500	ns
				DMV32		300	
				DMV56		300	
V_{FP}	Peak forward voltage	$I_F = 3\text{A}$ $dI_F/dt = 80\text{A}/\mu\text{s}$	$T_j = 100^\circ\text{C}$	DMV16		8	V
				DMV32		10	
				DMV56		10	

DMV series

ORDERING INFORMATION

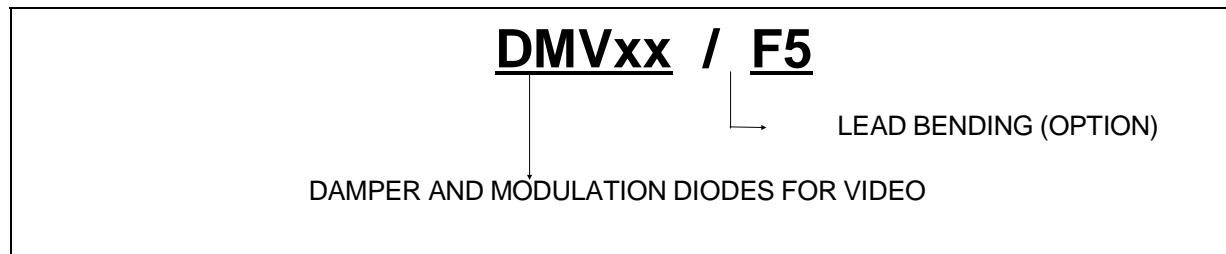


Fig. 1-1: Power dissipation versus peak forward current (triangular waveform, $\delta=0.45$) (damper diode.)

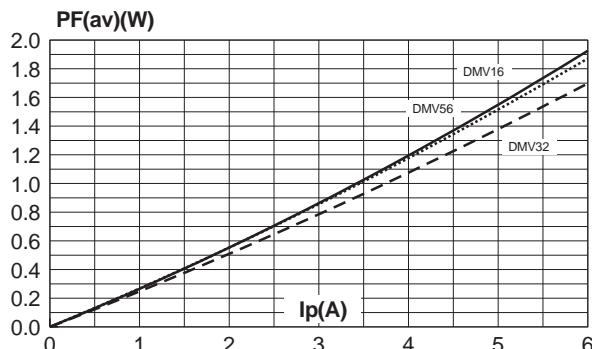


Fig. 1-2: Power dissipation versus peak forward current (triangular waveform, $\delta=0.45$) (modulation diode)

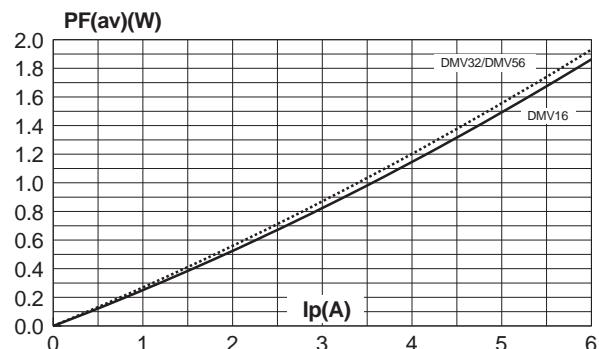


Fig. 2-1: Average forward current versus ambient temperature (damper diode).

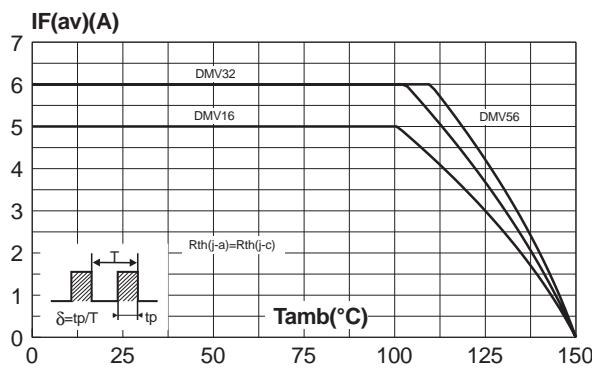
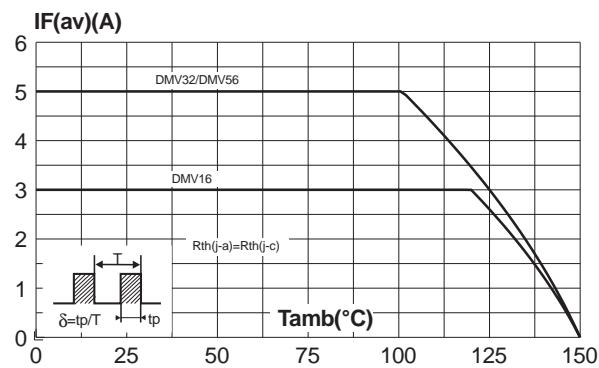


Fig. 2-2: Average forward current versus ambient temperature (modulation diode).



PACKAGE MECHANICAL DATA
TO-220AB

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

- cooling method: by conduction (c)
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1 m.N.

Type	Marking	Package	Weight	Base qty	Delivery mode
DMV16 DMV16/F5	DMV16	TO-220AB	2.2 g.	50	Tube
DMV32 DMV32/F5	DMV32	TO-220AB	2.2 g.	50	Tube
DMV56 DMV56/F5	DMV56	TO-220AB	2.2 g.	50	Tube

- Epoxy meets UL94, V0